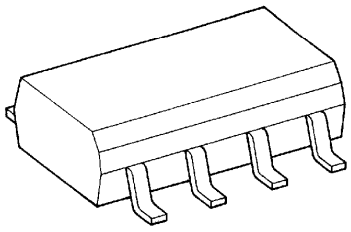
TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7W32F, TC7W32FU, TC7W32FK

DUAL 2-INPUT OR GATE

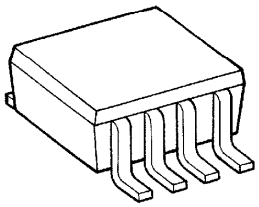
The TC7W32 is a high speed C^2MOS 2-INPUT OR GATE fabricated with silicon gate C^2MOS technology.
It achives the high speed operation similar to equivalent LSTTL while maintaining the C^2MOS low power dissipation.
The internal circuit is composed of 3 stages including buffer output, which enables high noise immunity and stable output.
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

TC7W32F



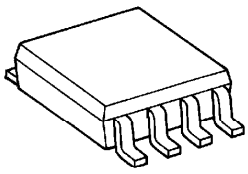
SOP8-P-1.27

TC7W32FU



SSOP8-P-0.65

TC7W32FK



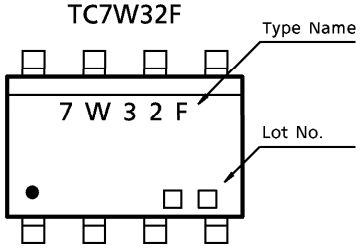
SSOP8-P-0.50A

FEATURES

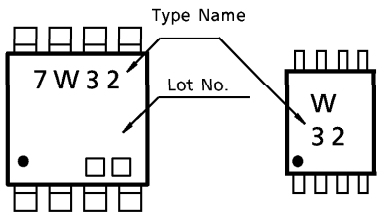
- High Speed ..... t_{pd} = 6ns (Typ.) at V_{CC} = 5V
- Low Power Dissipation ..... I_{CC} = 1μA (Max.) at Ta = 25°C
- High Noise Immunity ..... $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Output Drive Capability ..... 10 LSTTL Loads
- Symmetrical Output Impedance ... $|I_{OH}| = I_{OL}$ = 4mA (Min.)
- Balanced Propagation Delays ..... $t_{pLH} \fallingdotseq t_{pHL}$
- Wide Operating Voltage Range ... $V_{CC\,(opr)}$ = 2~6V

MARKING

TC7W32F



TC7W32FU TC7W32FK

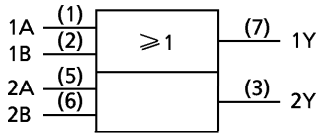


Weight
SOP8-P-1.27 : 0.05g (Typ.)
SSOP8-P-0.65 : 0.02g (Typ.)
SSOP8-P-0.50A : 0.01g (Typ.)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	−0.5~7	V
DC Input Voltage	V_{IN}	−0.5~V_{CC} + 0.5	V
DC Output Voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} / Ground Current	I_{CC}	± 25	mA
Power Dissipation	P_D	300 (FM8, SM8) 200 (US8)	mW
Storage Temperature	T_{stg}	−65~150	°C
Lead Temperature (10s)	T_L	260	°C

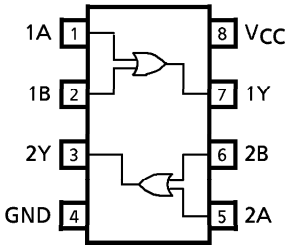
LOGIC DIAGRAM



TRUTH TABLE

A	B	Y
H	H	H
L	H	H
H	L	H
L	L	L

PIN ASSIGNMENT (TOP VIEW)



RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	2~6	V
Input Voltage	V_{IN}	0~V_{CC}	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	t_r, t_f	0~1000 (V_{CC} = 2.0V) 0~ 500 (V_{CC} = 4.5V) 0~ 400 (V_{CC} = 6.0V)	ns

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		V_{CC}	Ta = 25°C MIN.	TYP.	MAX.	Ta = −40~85°C MIN.	MAX.	UNIT
High-Level Input Voltage	V_{IH}	—		2.0	1.5	—	—	1.5	—	V
				4.5	3.15	—	—	3.15	—	
				6.0	4.2	—	—	4.2	—	
Low-Level Input Voltage	V_{IL}	—		2.0	—	—	0.5	—	0.5	V
				4.5	—	—	1.35	—	1.35	
				6.0	—	—	1.8	—	1.8	
High-Level Output Voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\mu A$	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
				6.0	5.9	6.0	—	5.9	—	
			$I_{OH} = -4mA$	4.5	4.18	4.31	—	4.13	—	
			$I_{OH} = -5.2mA$	6.0	5.68	5.80	—	5.63	—	
Low-Level Output Voltage	V_{OL}	$V_{IN} = V_{IL}$	$I_{OL} = 20\mu A$	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
				6.0	—	0.0	0.1	—	0.1	
			$I_{OL} = 4mA$	4.5	—	0.17	0.26	—	0.33	
			$I_{OL} = 5.2mA$	6.0	—	0.18	0.26	—	0.33	
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC}$ or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND		6.0	—	—	1.0	—	10.0	

AC ELECTRICAL CHARACTERISTICS ($C_L = 15pF$, $V_{CC} = 5V$, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	Ta = 25°C MIN.	TYP.	MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}	—	—	4	8	ns
Propagation Delay Time	t_{pLH} t_{pHL}	—	—	6	12	ns

AC ELECTRICAL CHARACTERISTICS ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V_{CC}	Ta = 25°C MIN.	TYP.	MAX.	Ta = −40~85°C MIN.	MAX.	UNIT
Output Transition Time	t_{TLH} t_{THL}	—	2.0	—	25	75	—	95	ns
			4.5	—	7	15	—	19	
			6.0	—	6	13	—	16	
Propagation Delay Time	t_{pLH} t_{pHL}	—	2.0	—	27	75	—	95	ns
			4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Input Capacitance	C_{IN}	—		—	5	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	(Note 1)		—	21	—	—	—	

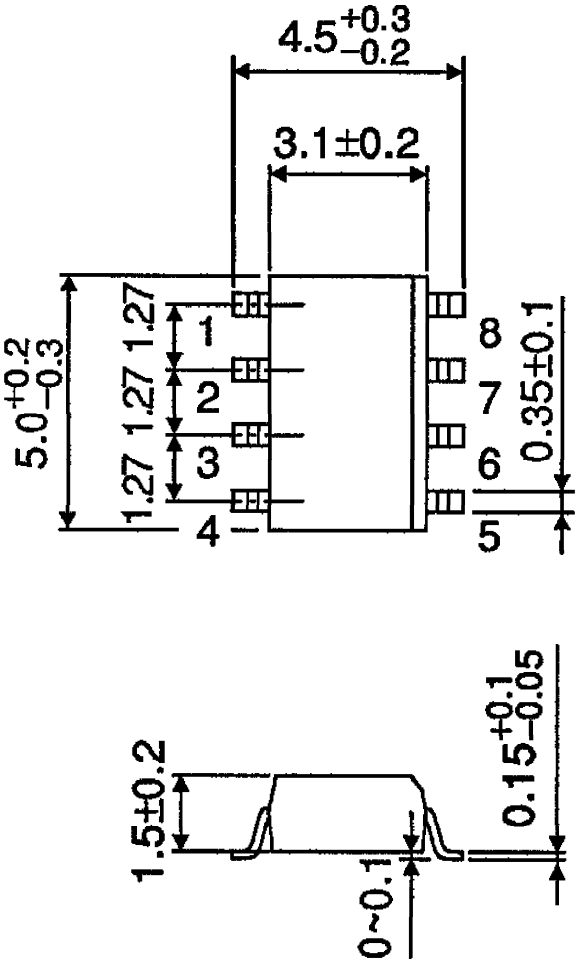
(Note 1) : CPD is defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit).

Average operating current can be obtained by the equation hereunder.

$$I_{CC\,(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 2 \text{ (per gate)}$$

PACKAGE DIMENSIONS

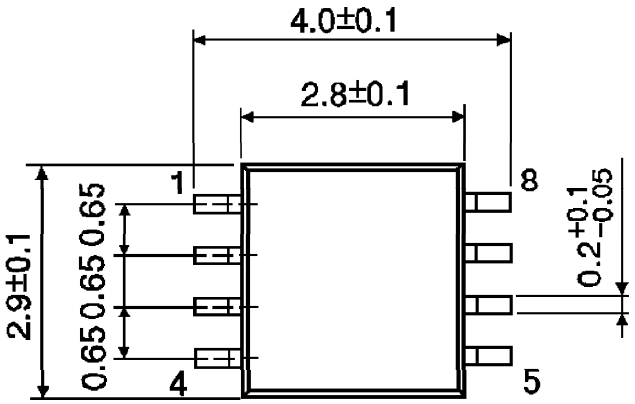
SOP8-P-1.27 Unit : mm

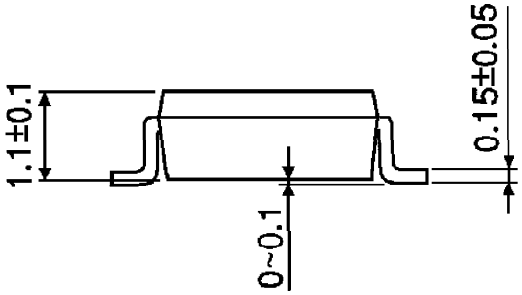


Weight : 0.05g (Typ.)

PACKAGE DIMENSIONS

SSOP8-P-0.65 Unit : mm



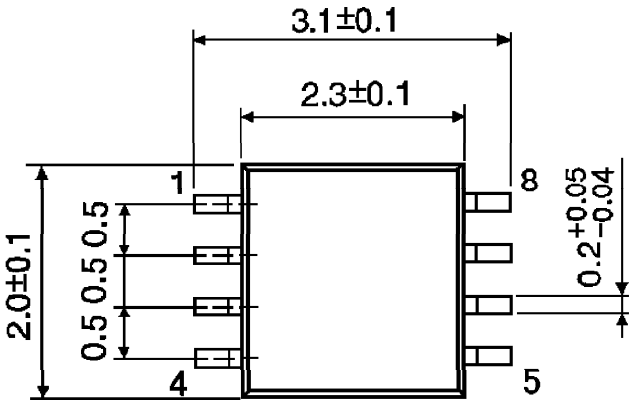


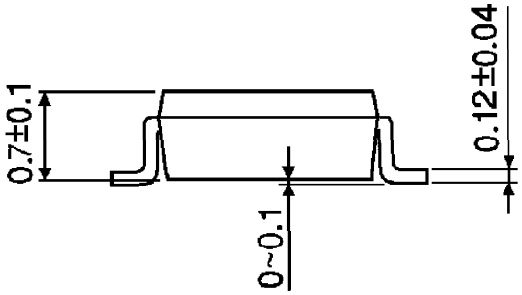
Weight : 0.02g (Typ.)

PACKAGE DIMENSIONS

SSOP8-P-0.50A

Unit : mm





Weight : 0.01g (Typ.)

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000707EBA

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